

# NLSX3378

## 4-Bit 20 Mb/s Dual-Supply Level Translator

The NLSX3378 is a 4-bit configurable dual-supply bidirectional auto sensing translator that does not require a directional control pin. The  $V_{CC}$  I/O and  $V_L$  I/O ports are designed to track two different power supply rails,  $V_{CC}$  and  $V_L$  respectively. The  $V_{CC}$  supply rail is configurable from 1.65 V to 4.5 V while  $V_L$  supply rail is configurable to 1.2 V to 4.1 V. This allows lower voltage logic signals on the  $V_L$  side to be translated into higher voltage logic signals on the  $V_{CC}$  side, and vice-versa.

The NLSX3378 translator has open-drain outputs with integrated 10 k $\Omega$  pullup resistors on the I/O lines. The integrated pullup resistors are used to pullup the I/O lines to either  $V_L$  or  $V_{CC}$ . The NLSX3378 is an excellent match for open-drain applications such as the I<sup>2</sup>C communication bus.

### Features

- Wide High-Side  $V_{CC}$  Operating Range: 1.65 V to 4.5 V  
Wide Low-Side  $V_L$  Operating Range: 1.2 V to 4.1 V
- High-Speed with 20 Mb/s Guaranteed Data Rate for  $V_L > 2.5$  V
- Low Bit-to-Bit Skew
- Enable Input and I/O Lines have Overvoltage Tolerant (OVT) to 4.5 V
- Nonpreferential Powerup Sequencing
- Integrated 10 k $\Omega$  Pullup Resistors
- Small Space Saving Package – 2.02 x 1.54 mm  $\mu$ Bump12
- This is a Pb-Free Device

### Typical Applications

- I<sup>2</sup>C, SMBus, PMBus
- Low Voltage ASIC Level Translation
- Mobile Phones, PDAs, Cameras

### Important Information

- ESD Protection for Power, Enable and I/O Pins:  
Human Body Model (HBM):  $\pm 2$  kV



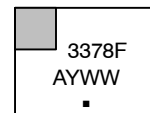
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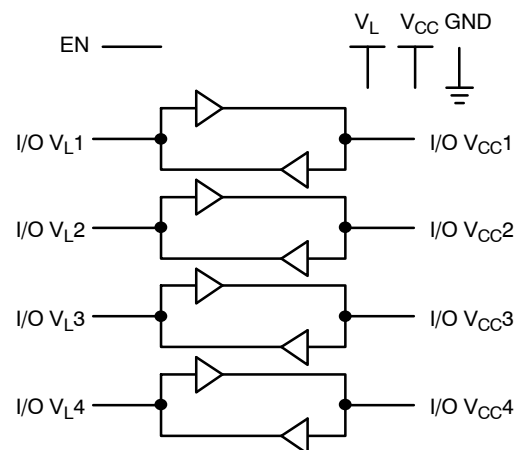
$\mu$ Bump12  
FC SUFFIX  
CASE 499AU

### MARKING DIAGRAM



- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

### LOGIC DIAGRAM



### ORDERING INFORMATION

Device	Package	Shipping†
NLSX3378FCT1G	$\mu$ Bump12 (Pb-Free)	3000/Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NLSX3378

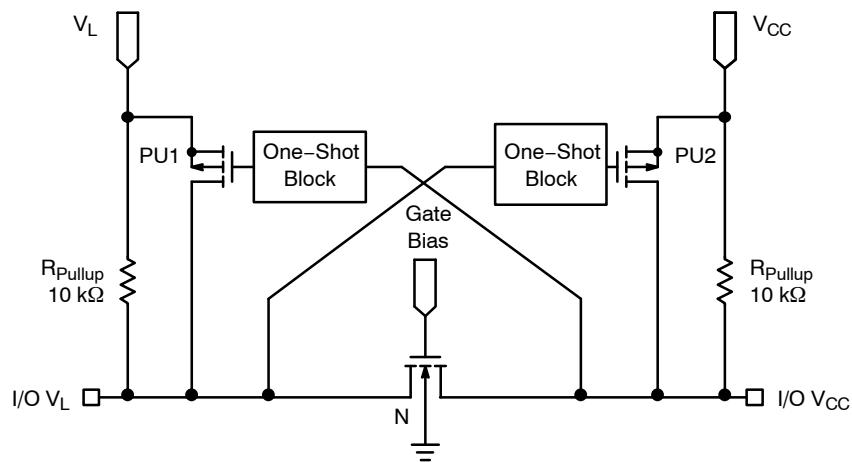


Figure 1. Block Diagram (1 I/O Line)

## PIN ASSIGNMENT

Pins	Description
V <sub>CC</sub>	V <sub>CC</sub> Input Voltage
V <sub>L</sub>	V <sub>L</sub> Input Voltage
GND	Ground
EN	Output Enable
I/O V <sub>CC</sub> <sub>n</sub>	V <sub>CC</sub> I/O Port, Referenced to V <sub>CC</sub>
I/O V <sub>L</sub> <sub>n</sub>	V <sub>L</sub> I/O Port, Referenced to V <sub>L</sub>

## FUNCTION TABLE

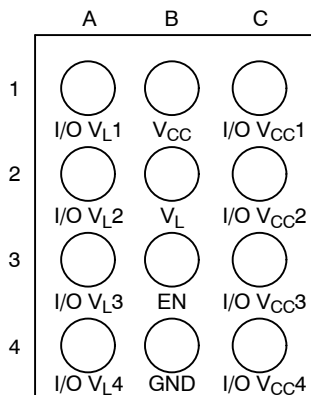
EN	Operating Mode
L	Hi-Z
H	I/O Buses Connected

## PIN LOCATION

Pin	Pin Name
A1	I/O V <sub>L</sub> 1
A2	I/O V <sub>L</sub> 2
A3	I/O V <sub>L</sub> 3
A4	I/O V <sub>L</sub> 4
B1	V <sub>CC</sub>
B2	V <sub>L</sub>
B3	EN
B4	GND
C1	I/O V <sub>CC</sub> 1
C2	I/O V <sub>CC</sub> 2
C3	I/O V <sub>CC</sub> 3
C4	I/O V <sub>CC</sub> 4

## μBump12

(2.02 x 1.54 mm)



(Bottom View)

**MAXIMUM RATINGS**

Symbol	Parameter	Value	Condition	Unit
V <sub>CC</sub>	High-side DC Supply Voltage	-0.3 to +7.0		V
V <sub>L</sub>	High-side DC Supply Voltage	-0.3 to +7.0		V
I/O V <sub>CC</sub>	V <sub>CC</sub> -Referenced DC Input/Output Voltage	-0.3 to (V <sub>CC</sub> + 0.3)		V
I/O V <sub>L</sub>	V <sub>L</sub> -Referenced DC Input/Output Voltage	-0.3 to (V <sub>L</sub> + 0.3)		V
V <sub>EN</sub>	Enable Control Pin DC Input Voltage	-0.3 to +7.0		V
I <sub>I/O_SC</sub>	Short-Circuit Duration (I/O V <sub>L</sub> and I/O V <sub>CC</sub> to GND)	40	Continuous	mA
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	High-side Positive DC Supply Voltage	1.65	4.5	V
V <sub>L</sub>	High-side Positive DC Supply Voltage	1.2	4.1	V
V <sub>EN</sub>	Enable Control Pin Voltage	GND	4.5	V
V <sub>IO</sub>	Enable Control Pin Voltage	GND	4.5	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C

**DC ELECTRICAL CHARACTERISTICS** (V<sub>CC</sub> = 1.65 V to 4.5 V and V<sub>L</sub> = 1.2 V to 4.1 V, unless otherwise specified)

Symbol	Parameter	Test Conditions	-40°C to +85°C			Unit
			Min	Typ (Notes 1, 2)	Max	
V <sub>IHC</sub>	I/O V <sub>CC</sub> Input HIGH Voltage		V <sub>CC</sub> - 0.4	-	-	V
V <sub>ILC</sub>	I/O V <sub>CC</sub> Input LOW Voltage		-	-	0.15	V
V <sub>IHL</sub>	I/O V <sub>L</sub> Input HIGH Voltage		V <sub>L</sub> - 0.2	-	-	V
V <sub>ILL</sub>	I/O V <sub>L</sub> Input LOW Voltage		-	-	0.15	V
V <sub>IH</sub>	Control Pin Input HIGH Voltage		V <sub>L</sub> - 0.2	-	-	V
V <sub>IL</sub>	Control Pin Input LOW Voltage		-	-	0.15	V
V <sub>OHC</sub>	I/O V <sub>CC</sub> Output HIGH Voltage	I/O V <sub>CC</sub> Source Current = 20 μA	2/3 * V <sub>CC</sub>	-	-	V
V <sub>OLC</sub>	I/O V <sub>CC</sub> Output LOW Voltage	I/O V <sub>CC</sub> Sink Current = 20 μA	-	-	1/3 * V <sub>CC</sub>	V
V <sub>OHL</sub>	I/O V <sub>L</sub> Output HIGH Voltage	I/O V <sub>L</sub> Source Current = 20 μA	2/3 * V <sub>L</sub>	-	-	V
V <sub>OLL</sub>	I/O V <sub>L</sub> Output LOW Voltage	I/O V <sub>L</sub> Sink Current = 20 μA	-	-	1/3 * V <sub>L</sub>	V
I <sub>QVCC</sub>	V <sub>CC</sub> Supply Current	I/O V <sub>CC</sub> and I/O V <sub>L</sub> Unconnected, V <sub>EN</sub> = V <sub>L</sub>	-	50	105	μA
I <sub>QVL</sub>	V <sub>L</sub> Supply Current	I/O V <sub>CC</sub> and I/O V <sub>L</sub> Unconnected, V <sub>EN</sub> = V <sub>L</sub>	-	0.1	1.0	μA
I <sub>TS-VCC</sub>	V <sub>CC</sub> Tristate Output Mode Supply Current	I/O V <sub>CC</sub> and I/O V <sub>L</sub> Unconnected, V <sub>EN</sub> = GND	-	0.1	2.5	μA
I <sub>TS-VL</sub>	V <sub>L</sub> Tristate Output Mode Supply Current	I/O V <sub>CC</sub> and I/O V <sub>L</sub> Unconnected, V <sub>EN</sub> = GND	-	0.1	2.5	μA
I <sub>OZ</sub>	I/O Tristate Output Mode Leakage Current	T <sub>A</sub> = +25°C	-	-	1.0	μA
R <sub>PU</sub>	Pullup Resistor I/O V <sub>L</sub> and V <sub>CC</sub>	T <sub>A</sub> = +25°C	-	10	-	kΩ

1. Typical values are for V<sub>CC</sub> = +2.8 V, V<sub>L</sub> = +1.8 V and T<sub>A</sub> = +25°C.
2. All units are production tested at T<sub>A</sub> = +25°C. Limits over the operating temperature range are guaranteed by design.

# NLSX3378

## TIMING CHARACTERISTICS – RAIL-TO-RAIL DRIVING CONFIGURATIONS

(I/O test circuit of Figures 2 and 3,  $C_{LOAD} = 15 \text{ pF}$ , driver output impedance  $\leq 50 \Omega$ ,  $R_{LOAD} = 1 \text{ M}\Omega$ )

Symbol	Parameter	Test Conditions	-40°C to +85°C (Note 3)			Unit
			Min	Typ	Max	
<b>+1.2 ≤ V<sub>L</sub> ≤ V<sub>CC</sub> ≤ +4.5 V</b>						
t <sub>RVCC</sub>	I/O V <sub>CC</sub> Risetime				25	ns
t <sub>FVCC</sub>	I/O V <sub>CC</sub> Falltime				37	ns
t <sub>RVL</sub>	I/O V <sub>L</sub> Risetime				30	ns
t <sub>FVL</sub>	I/O V <sub>L</sub> Falltime				30	ns
t <sub>PDVL-VCC</sub>	Propagation Delay (Driving I/O V <sub>L</sub> )				30	ns
t <sub>PDVCC-VL</sub>	Propagation Delay (Driving I/O V <sub>CC</sub> )				30	ns
t <sub>PPSKEW</sub>	Part-to-Part Skew				20	nS
MDR	Maximum Data Rate		8			Mb/s

### +1.2 ≤ V<sub>L</sub> ≤ V<sub>CC</sub> ≤ +3.3 V

t <sub>RVCC</sub>	I/O V <sub>CC</sub> Risetime				25	ns
t <sub>FVCC</sub>	I/O V <sub>CC</sub> Falltime				30	ns
t <sub>RVL</sub>	I/O V <sub>L</sub> Risetime				30	ns
t <sub>FVL</sub>	I/O V <sub>L</sub> Falltime				30	ns
t <sub>PDVL-VCC</sub>	Propagation Delay (Driving I/O V <sub>L</sub> )				20	ns
t <sub>PDVCC-VL</sub>	Propagation Delay (Driving I/O V <sub>CC</sub> )				20	ns
t <sub>PPSKEW</sub>	Part-to-Part Skew				10	nS
MDR	Maximum Data Rate		10			Mb/s

### +1.8 ≤ V<sub>L</sub> ≤ V<sub>CC</sub> ≤ +2.5 V

t <sub>RVCC</sub>	I/O V <sub>CC</sub> Risetime				15	ns
t <sub>FVCC</sub>	I/O V <sub>CC</sub> Falltime				15	ns
t <sub>RVL</sub>	I/O V <sub>L</sub> Risetime				15	ns
t <sub>FVL</sub>	I/O V <sub>L</sub> Falltime				15	ns
t <sub>PDVL-VCC</sub>	Propagation Delay (Driving I/O V <sub>L</sub> )				15	ns
t <sub>PDVCC-VL</sub>	Propagation Delay (Driving I/O V <sub>CC</sub> )				15	ns
t <sub>PPSKEW</sub>	Part-to-Part Skew				10	nS
MDR	Maximum Data Rate		16			Mb/s

### +2.5 ≤ V<sub>L</sub> ≤ V<sub>CC</sub> ≤ +3.3 V

t <sub>RVCC</sub>	I/O V <sub>CC</sub> Risetime				15	ns
t <sub>FVCC</sub>	I/O V <sub>CC</sub> Falltime				15	ns
t <sub>RVL</sub>	I/O V <sub>L</sub> Risetime				15	ns
t <sub>FVL</sub>	I/O V <sub>L</sub> Falltime				15	ns
t <sub>PDVL-VCC</sub>	Propagation Delay (Driving I/O V <sub>L</sub> )				15	ns
t <sub>PDVCC-VL</sub>	Propagation Delay (Driving I/O V <sub>CC</sub> )				15	ns
t <sub>PPSKEW</sub>	Part-to-Part Skew				10	nS
MDR	Maximum Data Rate		20			Mb/s

3. All units are production tested at T<sub>A</sub> = +25°C. Limits over the operating temperature range are guaranteed by design.

# NLSX3378

## TIMING CHARACTERISTICS – OPEN DRAIN DRIVING CONFIGURATIONS

(I/O test circuit of Figures 4 and 5,  $C_{LOAD} = 15 \text{ pF}$ , driver output impedance  $\leq 50 \Omega$ ,  $R_{LOAD} = 1 \text{ M}\Omega$ )

Symbol	Parameter	Test Conditions	-40°C to +85°C (Note 4)			Unit
			Min	Typ	Max	
<b>+1.2 ≤ V<sub>L</sub> ≤ V<sub>CC</sub> ≤ +4.5 V</b>						
t <sub>RVCC</sub>	I/O V <sub>CC</sub> Risetime				400	ns
t <sub>FVCC</sub>	I/O V <sub>CC</sub> Falltime				50	ns
t <sub>RVL</sub>	I/O V <sub>L</sub> Risetime				400	ns
t <sub>FVL</sub>	I/O V <sub>L</sub> Falltime				60	ns
t <sub>PDVL-VCC</sub>	Propagation Delay (Driving I/O V <sub>L</sub> )				1000	ns
t <sub>PDVCC-VL</sub>	Propagation Delay (Driving I/O V <sub>CC</sub> )				1000	ns
t <sub>PPSKEW</sub>	Part-to-Part Skew				50	nS
MDR	Maximum Data Rate		2			Mb/s

4. All units are production tested at  $T_A = +25^\circ\text{C}$ . Limits over the operating temperature range are guaranteed by design. Limits over the operating temperature range are guaranteed by design.

# NLSX3378

## TEST SETUPS

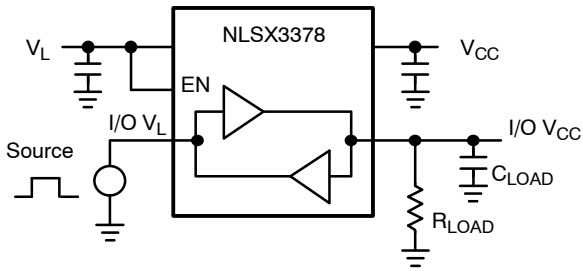


Figure 2. Rail-to-Rail Driving I/O VL

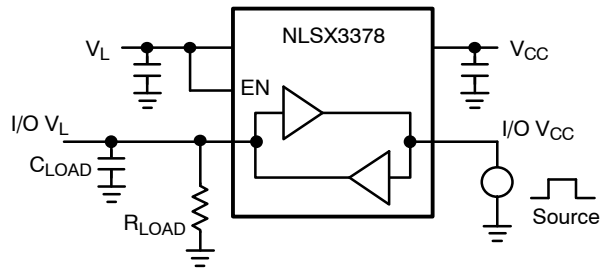


Figure 3. Rail-to-Rail Driving I/O VCC

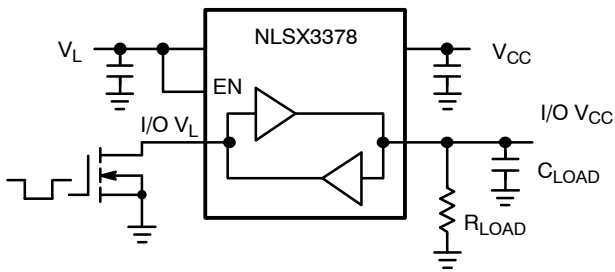


Figure 4. Open-Drain Driving I/O VL

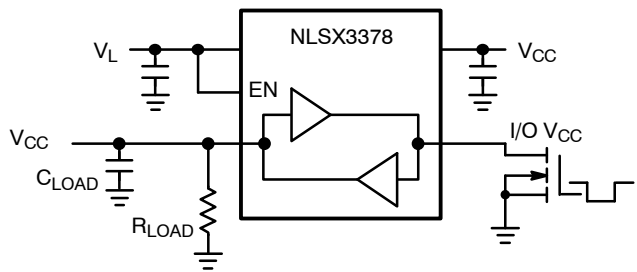


Figure 5. Open-Drain Driving I/O VCC

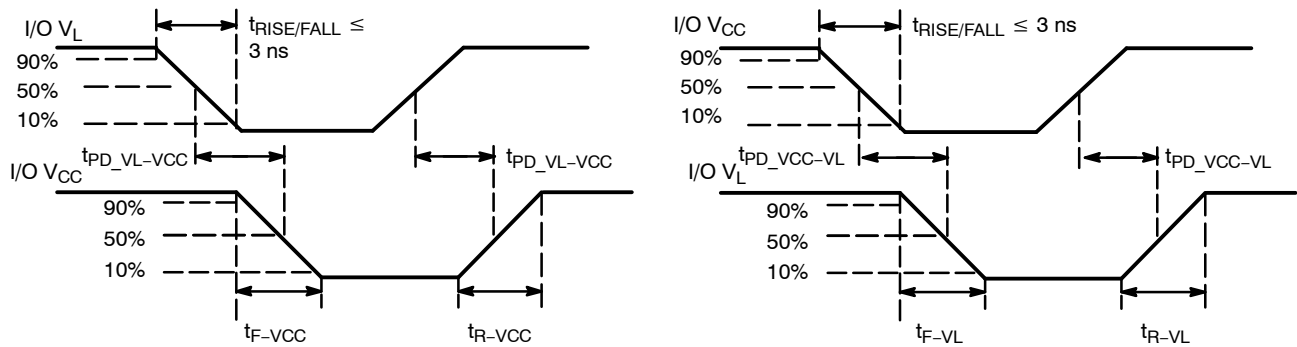
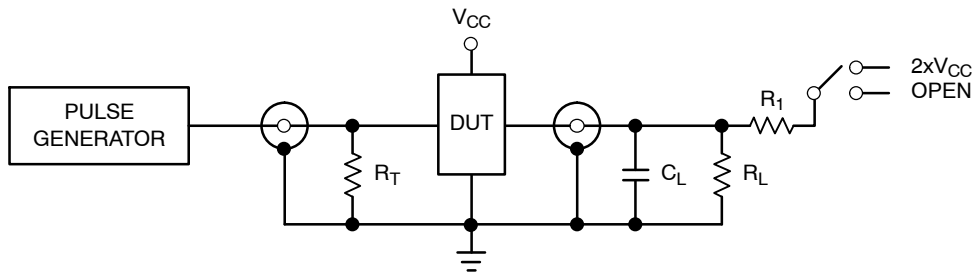


Figure 6. Definition of Timing Specification Parameters

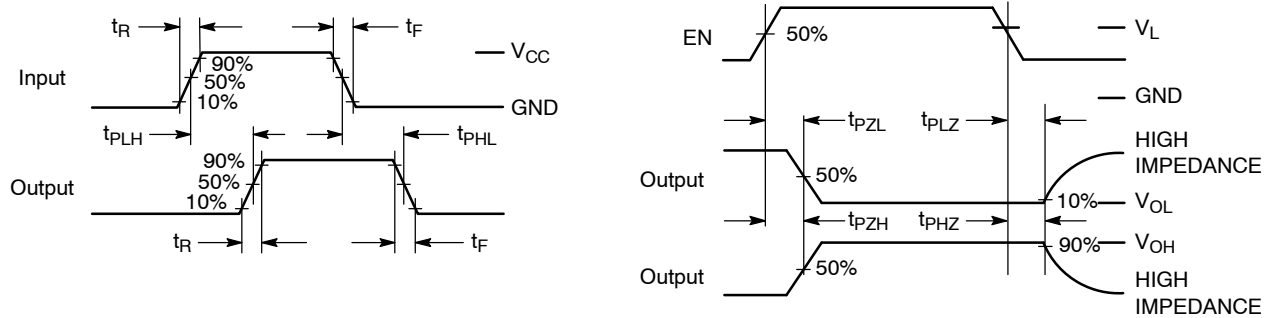
# NLSX3378



Test	Switch
$t_{PZH}$ , $t_{PHZ}$	Open
$t_{PZL}$ , $t_{PLZ}$	$2 \times V_{CC}$

$C_L = 15 \text{ pF}$  or equivalent (Includes jig and probe capacitance)  
 $R_L = R_1 = 50 \text{ k}\Omega$  or equivalent  
 $R_T = Z_{OUT}$  of pulse generator (typically  $50 \Omega$ )

**Figure 7. Test Circuit for Enable/Disable Time Measurement**



**Figure 8. Timing Definitions for Propagation Delays and Enable/Disable Measurement**

## APPLICATIONS INFORMATION

### Level Translator Architecture

The NLSX3378 auto sense translator provides bi-directional voltage level shifting to transfer data in multiple supply voltage systems. This device has two supply voltages,  $V_L$  and  $V_{CC}$ , which set the logic levels on the input and output sides of the translator. When used to transfer data from the  $V_L$  to the  $V_{CC}$  ports, input signals referenced to the  $V_L$  supply are translated to output signals with a logic level matched to  $V_{CC}$ . In a similar manner, the  $V_{CC}$  to  $V_L$  translation shifts input signals with a logic level compatible to  $V_{CC}$  to an output signal matched to  $V_L$ .

The NLSX3378 consists of two bi-directional channels that independently determine the direction of the data flow without requiring a directional pin. The one-shot circuits are used to detect the rising or falling input signals. In addition, the one shots decrease the rise and fall time of the output signal for high-to-low and low-to-high transitions.

Each input/output channel has an internal 10 k $\Omega$  pull. The magnitude of the pullup resistors can be reduced by connecting external resistors in parallel to the internal 10 k $\Omega$  resistors.

### Input Driver Requirements

The rise ( $t_R$ ) and fall ( $t_F$ ) timing parameters of the open drain outputs depend on the magnitude of the pull-up resistors. In addition, the propagation times ( $t_{PD}$ ), skew ( $t_{PSKEW}$ ) and maximum data rate depend on the impedance of the device that is connected to the translator. The timing parameters listed in the data sheet assume that the output impedance of the drivers connected to the translator is less than 50 k $\Omega$ .

### Enable Input (EN)

The NLSX3378 has an Enable pin (EN) that provides tri-state operation at the I/O pins. Driving the Enable pin to a low logic level minimizes the power consumption of the device and drives the I/O  $V_{CC}$  and I/O  $V_L$  pins to a high impedance state. Normal translation operation occurs when the EN pin is equal to a logic high signal. The EN pin is referenced to the  $V_L$  supply and has Overvoltage Tolerant (OVT) protection.

### Power Supply Guidelines

During normal operation, supply voltage  $V_L$  should be less than or equal to  $V_{CC}$ . The sequencing of the power supplies will not damage the device during the power up operation.

The enable pin should be used to enter the low current tri-state mode, rather than setting either the  $V_L$  or  $V_{CC}$  supplies to 0 V. The NLSX3378 will not be damaged if either  $V_L$  or  $V_{CC}$  is equal to 0 V while the other supply voltage is at a nominal operating value; however, the operation of the translator cannot be guaranteed during single supply operation.

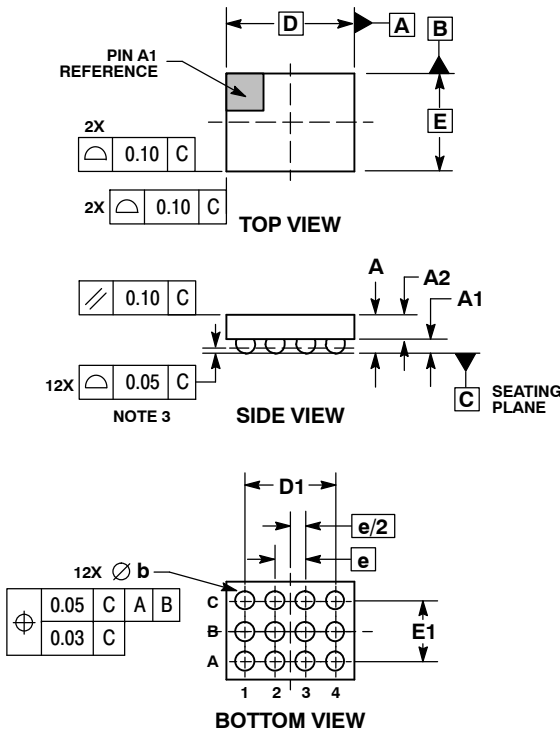
For optimal performance, 0.01  $\mu$ F to 0.1  $\mu$ F decoupling capacitors should be used on the  $V_L$  and  $V_{CC}$  power supply pins. Ceramic capacitors are a good design choice to filter and bypass any noise signals on the voltage lines to the ground plane of the PCB. The noise immunity will be maximized by placing the capacitors as close as possible to the supply and ground pins, along with minimizing the PCB connection traces.



# NLSX3378

## PACKAGE DIMENSIONS

**μBump12, 2.02x1.54, 0.5P**  
**CASE 499AU-01**  
**ISSUE O**



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

DIM	MILLIMETERS	
	MIN	MAX
A	---	0.66
A1	0.21	0.27
A2	0.33	0.39
b	0.29	0.34
D	2.02 BSC	
D1	1.50 BSC	
E	1.54 BSC	
E1	1.00 BSC	
e	0.50 BSC	

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